

## MSW205x-205

Rev. V3

#### Features

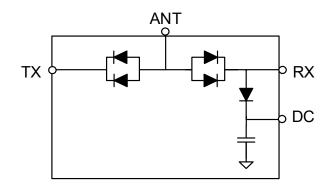
- Wide Frequency Range: 50 MHz to 4 GHz, in 2 bands
- Surface Mount SP2T Switch in Compact Outline: 8 mm L x 5 mm W x 2.5 mm H
- Higher Average Power Handling than Plastic Packaged
- MMIC Switches: 158 W CW
- High RF Peak Power: 630 W
- Low Insertion Loss: 0.25 dB
- High IIP3: 65 dBm
- Operates From Positive Voltage Only: 5 V & 28 V to 125 V
- Ultra-Thin Termination Plating to Combat Embrittlement
- RoHS\* Compliant

#### Description

The MSW2050-205 (50 MHz - 1 GHz) and MSW2051-205 (400 MHz - 4 GHz) series of surface mount silicon PIN diode SP2T switches can be used for high power transmit/receive (TR) switching or active receiver protection. These switches are manufactured using a proven hybrid manufacturing process incorporating high voltage PIN diodes and passive devices integrated on a ceramic substrate. low profile, compact, surface mount These components offer superior small and large signal performance compared to that of MMIC devices in QFN packages. The SP2T switches are designed in an asymmetrical topology to minimize Tx-Ant loss and maximize Tx-Rx isolation performance. The very low thermal resistance (<15°C/W) of the PIN diodes in these devices enables them to reliably handle RF incident power levels of 50 dBm CW and RF peak incident power levels of 58 dBm in cold switching applications at  $T_A = 25^{\circ}C$ . The low PIN diode series resistance (<1.0  $\Omega$ ), coupled with their long minority carrier lifetime, (>1.5 µs), provides input third order intercept point (IIP3) greater than 65 dBm.

These MSW2050-205, MSW2051-205 SP2T switches are designed to be used in high average and peak power switch applications, operating from 50 MHz to 4 GHz in two bands, which utilize high volume, surface mount, solder re-flow manufacturing. These products are durable and capable of reliably operating in military, commercial, and industrial environments.

#### **Functional Schematic**



#### **Ordering Information**

Part Number	Package
MSW2050-205-T	tube
MSW2050-205-R	250 or 500 piece reel
MSW2050-205-W	Waffle pack
MSW2051-205-T	tube
MSW2051-205-R	250 or 500 piece reel
MSW2051-205-W	Waffle pack
MSW2050-205-E	RF evaluation board
MSW2051-205-E	RF evaluation board

\* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

1

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.



# MSW205x-205

Rev. V3

### MSW2050-205 Electrical Specifications: $T_A = +25^{\circ}C$ , $P_{IN} = 0$ dBm, $Z_0 = 50 \Omega$

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Frequency	—	MHz	50	—	1000
Insertion Loss	Condition 1 Condition 2	dB	_	0.15 0.25	0.25 0.35
Return Loss	Condition 1 Condition 2	dB	18 20	20 22	_
Isolation	Condition 1 Condition 2	dB	47 23	50 26	—
TX CW Incident Power <sup>1</sup>	Condition 1, Source & Load VSWR = 1.5:1	dBm		_	52
RX CW Incident Power <sup>1</sup>	Condition 2, Source & Load VSWR = 1.5:1	dBm	—	—	43
Peak Incident Power <sup>1</sup>	Source & Load VSWR = $1.5:1$ Pulse Width = $10 \mu$ s, Duty Cycle = $1\%$	dBm		_	58
Switching Time <sup>2</sup>	10% -90% RF Voltage, TTL rep rate = 100 kHz	μs		2	3
Input IP3	F1 = 500 MHz, F2 = 510 MHz P1 = P2 = 40 dBm	dBm	60	65	_

#### MSW2051-205 Electrical Specifications: $T_A = +25^{\circ}C$ , $P_{IN} = 0$ dBm, $Z_0 = 50 \Omega$

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Frequency	—	MHz	400	—	4000
Insertion Loss	Condition 1 Condition 2	dB	_	0.3 0.8	0.4 0.9
Return Loss	Condition 1 Condition 2	dB	15 15	17 17	_
Isolation	Condition 1 Condition 2	dB	32 11	34 13	
TX CW Incident Power <sup>1</sup>	Condition 1, Source & Load VSWR = 1.5:1	dBm	_	—	52
RX CW Incident Power <sup>1</sup>	Condition 2, Source & Load VSWR = 1.5:1	dBm	_	—	43
Peak Incident Power <sup>1</sup>	Source & Load VSWR = 1.5:1 Pulse Width = 10 μs, Duty Cycle = 1%	dBm	_	_	58
Switching Time <sup>2</sup> T-Rise	10% -90% RF Voltage, TTL rep rate = 100 kHz	μs	_	1.5	2.0
Input IP3	F1 = 2.0 GHz, F2 = 2.01 GHz P1 = P2 = 40 dBm	dBm	60	65	_

 PIN diode minimum reverse DC voltage (V<sub>HIGH</sub>) to maintain high resistance in the OFF PIN diode is determined by RF frequency, incident power, duty cycle, characteristic impedance and VSWR as well as by the characteristics of the diode. The recommended minimum reverse bias voltage (V<sub>HIGH</sub>) values are provided in the Minimum Reverse Bias Voltage table of this datasheet.

bias voltage (V<sub>HIGH</sub>) values are provided in the Minimum Reverse Bias Voltage table of this datasheet.
Switching time (10/90% RF Voltage t-rise and 90/10% RF Voltage t-fall) is a function of the PIN diode driver performance as well as the characteristics of the diode. An RC "current spiking network" is used on the driver output to provide a transient current to rapidly remove stored charge from the PIN diode. Typical component values are: R = 50 to 220 Ω and C = 470 to 1,000 pF.

<sup>2</sup> 

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.



## MSW205x-205

Rev. V3

#### Evaluation Board Truth Table<sup>3,4</sup>

Bias State	RF State	Ant Bias (P1-pin 3)	TX Bias (P1-pin 1)	RX Bias (P1-pin 7)	DC Bias (P1-pin 5)
Condition 1	TX-ANT Low Loss & TX-RX Isolation	+5 V @ +100 mA	0 V @ +100 mA	+28 V @ +25 mA	0 V @ +25 mA
Condition 2	ANT-RX Low Loss & RX-TX Isolation	+5 V @ +100 mA	+28 V @ 0 mA	0 V @ +100 mA	+28 V @ 0 mA

3. 28 V</= V<sub>HIGH</sub> </= 125 V.

4. PIN diode minimum reverse DC voltage (V<sub>HIGH</sub>) to maintain high resistance in the OFF PIN diode is determined by RF frequency, incident power, duty cycle, characteristic impedance and VSWR as well as by the characteristics of the diode. The recommended minimum reverse bias voltage (V<sub>HIGH</sub>) values are provided in the Minimum Reverse Bias Voltage table of this datasheet.

#### **RF Bias Network Component Values**

Part #	Frequency (MHz)	Inductors	DC Blocking Capacitors	RF Bypass Capacitors
MSW2050-205	50 - 1000	4.7 µH	0.1 µF	0.1 µF
MSW2051-205	400 - 4000	82 nH	27 pF	270 pF

## Minimum Reverse Bias Voltage⁵

#### $P_{INC}$ = 125 W CW, $Z_0$ = 50 $\Omega$ with 1.5:1 Combined Source and Load VSWR

Part #	20 MHz	100 MHz	200 MHz	400 MHz	1 GHz	4 GHz
MSW2050-205	125 V	125 V	85 V	55 V	28 V	N/A
MSW2051-205	N/A	N/A	125 V	85 V	55 V	28 V

5. N/A denotes the switch is not recommended for that frequency band.

The minimum reverse bias voltage required to maintain a PIN diode out of conduction in the presence of a large RF signal is given by:

$$|V_{DC}| = \frac{|V_{RF}|}{\sqrt{1 + \left[\left(\frac{0.0142 \times f_{MHz} \times W_{mils}^2}{V_{RF} \times \sqrt{D}}\right) \times \left(1 + \sqrt{1 + \left(\frac{0.056 \times V_{RF} \times \sqrt{D}}{W_{mils}}\right)^2}\right)\right]^2}}$$

Where:

R. Caverly and G. Hiller, —Establishing the Minimum Reverse Bias for a PIN Diode in a High Power Switch, IEEE Transactions on Microwave Theory and Techniques, Vol.38, No.12, December 1990

3

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.



#### **Absolute Maximum Ratings**

Parameter	Conditions	Absolute Maximum
Forward Current	Ant, TX or RX Port DC Port	250 mA 150 mA
Reverse Voltage	TX or RX Port DC Port	200 V 200 V
Forward Diode Voltage	I <sub>F</sub> = 250 mA	1.2 V
CW Incident Power Handling <sup>4</sup>	TX or Ant Port Combined Source & Load VSWR = 1.5:1, $T_c = 85^{\circ}C$ , cold switching	52 dBm
CW Incident Power Handling <sup>4</sup>	RX or Ant Port Combined Source & Load VSWR = 1.5:1, T <sub>c</sub> = 85°C, cold switching	43 dBm
Peak Incident Power Handling <sup>4</sup>	RX or Ant Port Combined Source & Load VSWR = 1.5:1, T <sub>C</sub> = 85°C, cold switching, Pulse Width = 10 μs, Duty Cycle = 1%	58 dBm
Total Dissipated RF & DC Power <sup>4</sup>	$T_{C}$ = 85°C, cold switching	8 W
Junction Temperature	_	+175°C
Operating Temperature	_	-55°C to +125°C
Storage Temperature	_	-65°C to +150°C
Assembly Temperature	t = 10 s	+260°C

6. Backside RF and DC grounding area of device must be completely solder attached to the RF circuit board vias for proper electrical and thermal circuit grounding.

#### **Handling Procedures**

Please observe the following precautions to avoid damage:

#### Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 1C (HBM) devices. The moisture sensitivity level (MSL) rating for this part is MSL 1.

#### **Environmental Capabilities**

The MSW204x-204 diode is capable of meeting the environmental requirements of MIL-STD-202 and MIL-STD-750.

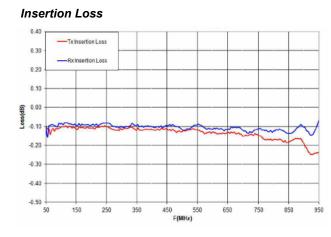
<sup>4</sup> 

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.

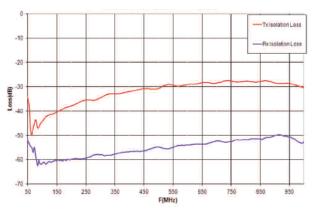


## **Typical Performance Curves**

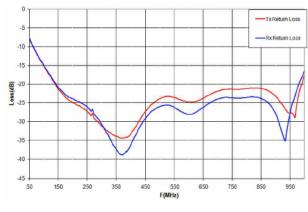
#### MSW2050-205



Isolation

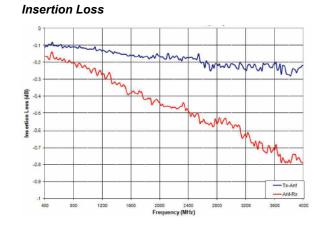


#### **Return Loss**

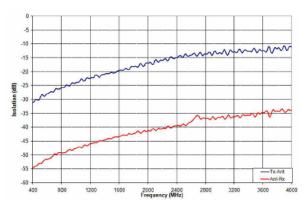


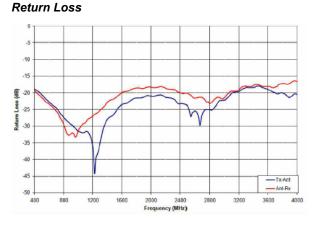
5

MSW2051-205



Isolation



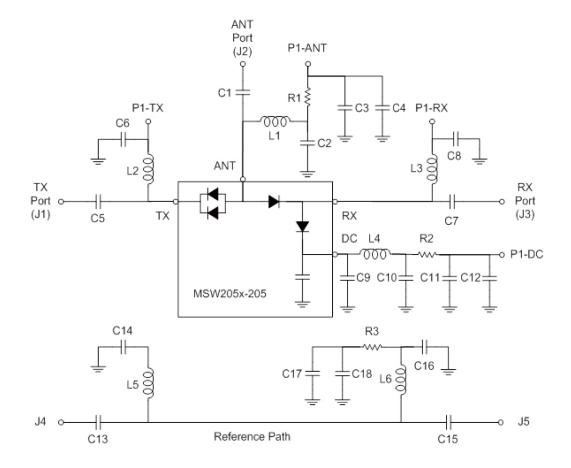


#### MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.

For further information and support please visit: <u>https://www.macom.com/support</u>



#### **SP2T Switch Evaluation Board Schematic**



The evaluation boards for the MSW2050 family of surface mount silicon PIN diode SP2T T-R switches allow the full exercise of each switch for small signal performance analysis, as well as for large signal operation with maximum input signal power of 45 dBm (CW or peak power). Each evaluation board includes the appropriate MSW205x-205 switch, DC blocking capacitors at each RF port and bias decoupling networks at each RF port which allow DC or low frequency control signals to be applied to the switch.

Three complementary control signals are required for proper operation. Bias voltages are applied to the TX bias port, RX bias port and the DC bias port to control the state of the switch. A bias voltage of 5 V must be applied to the Ant Bias (pin 3 of multi-pin connector P1) port whenever the switch is in operation.

For further information and support please visit: <u>https://www.macom.com/support</u>

6



#### **Transmit State**

In the TX state, the series PIN diode between the ANT and TX ports is forward biased by applying 0 V to the TX bias input port (pin 1 of multi-pin connector P1). The magnitude of the resultant bias current through the diode is primarily determined by the voltage applied to the ANT bias port (pin 3 of J1), the magnitude of the forward voltage across the PIN diode and the resistance of R1. This current is nominally 100 mA. At the same time, the PIN diode connected between RX and DC ports is also forward biased by applying a higher bias voltage, nominally 28 V, to the RX bias port (pin 7 of P1) and 0 V to the DC bias port (pin 5 of P1). Under this condition, the PIN diode connected between the ANT and RX port is reverse biased and the PIN diode connected between the RX and DC ports is forward biased. The magnitude of the bias current through this diode is primarily determined by the voltage applied to the RX bias port, the magnitude of the forward voltage across the PIN diode and the resistance of R2. This current is nominally 25 mA.

The RX series PIN diode, which is connected between the ANT and RX ports, must be reverse biased during the transmit state. The reverse bias voltage must be sufficiently large to maintain the diode in its non-conducting, high impedance state when large RF signal voltage may be present in the ANT-to-TX path. The reverse voltage across this diode is the arithmetic difference of the bias voltage applied to the RX bias port and the DC forward voltage of the forward-biased transmit series PIN diode.

The minimum voltage required to maintain the series diode on the RX side of the switch out of conduction is a function of the magnitude of the RF voltage present, the standing wave present at the RX series diode's anode, the frequency of the RF signal and the characteristics of the RX series diode, among other factors. Minimum control voltages for several signal frequencies are shown in the table "Minimum Reverse Bias Voltage", assuming the input power to the RX or ANT port to be 100 W CW and the VSWR on the ANT-TX path to be 1.5:1. It is important to note that the evaluation board, as supplied from the factory, is not capable of handling RF input signals larger than 45 dBm. If performance of the switch under larger input signals is to be evaluated, an adequate heat sink must be properly attached to the

evaluation board, and several of the passive components on the board must be changed in order to safely handle the dissipated power as well as the high bias voltage necessary for proper performance. Contact the factory for recommended components and heat sink.

#### **Receive State**

In the RX state, the series PIN diode between the ANT and RX ports is forward biased by applying 0 V to the RX bias input port (pin 7 of multi-pin connector P1). The magnitude of the resultant bias current through the diode is primarily determined by the voltage applied to the ANT bias port (pin 3 of P1), the magnitude of the forward voltage across the PIN diode and the resistance of R1. This current is nominally 100 mA. At the same time, the PIN diode connected between RX and DC ports is reverse biased by applying a high bias voltage, nominally 28 V. to the DC bias port (pin 5 of P1). A high voltage, nominally 28 V, is also applied to the TX bias port (pin 1 of P1). Under this condition, the PIN diode connected between the ANT and TX port is reverse biased thus isolating the TX RF port from the RX signal path. The reverse voltage across this diode is the arithmetic difference of the bias voltage applied to the TX bias port and the DC forward voltage of the forward-biased receive series PIN diode. The minimum voltage required to maintain the series diode on the TX side of the switch out of conduction is a function of the magnitude of the RF voltage present, the standing wave present at the RX series diode's anode, the frequency of the RF signal and the characteristics of the TX series diode, among other factors. For typical receive-level signals, this diode is held out of conduction with a relatively small reverse bias voltage.

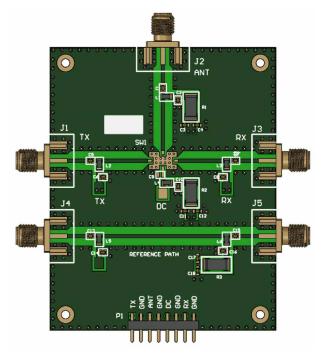
The values of the reactive components which comprise the bias decoupling networks as well as the signal path DC blocking are shown in the table RF Bias Network Component Values.

#### **Reference Path**

A reference path is provided on the evaluation board, complete with bias decoupling networks, so that the magnitude of the insertion loss of the microstrip transmission lines connected to the switch and the associated bias decoupling components can be measured and removed from the measured performance of the switch.

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.





#### **SP2T Switch Evaluation Board Layout**

#### **Evaluation Board Parts List**

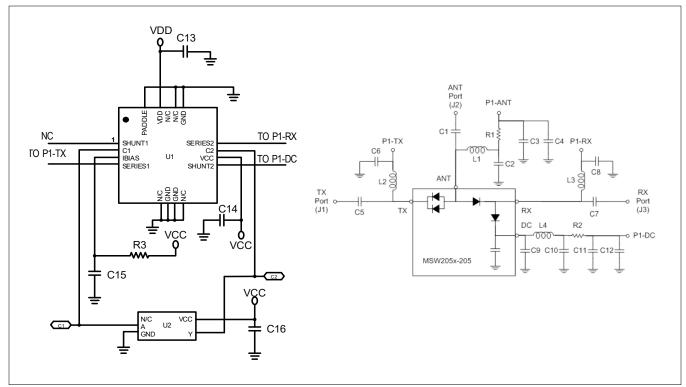
MSW2050-205 Band 1				
Part	Value	Case Style		
C1, C2, C5 - C8, C13 - C15	0.1 µF	0603		
<sup>7</sup> C3, C4, C11, C12, C17, C18	0.1 µF	0603		
L1 - L6	1.7 µH	0603		
R1, R3	39 Ω	2512		
R2	1200 Ω	2512		

MSW2051-205 Band 2				
Part	Value	Case Style		
C1, C5, C7, C13, C15	47 pF	0603		
C2, C6, C8, C9, C10, C14, C16	220 pF	0603		
C3, C4, C11, C12, C17, C18	1000 pF	0603		
L1 - L6	43 nH	0603		
R1, R3	39 Ω	2512		
R2	1200 Ω	2512		

7. Second bypass capacitor is optional.

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.





## MSW205x-205 with MADR-010574 Driver Application Schematic<sup>8</sup>

8. See page 8 for R1, L1 - L4 and C1 - C12 values. P1-ANT set to  $V_{\text{CC}}.$ 

#### MADR-010574 Parts List

Part	Value
C13	0.01 µF
C14 - C16	0.1 µF
R2, R4 <sup>9</sup>	12 ΚΩ
R3	499 ΚΩ
U2	SN74AHC1G

9. Resistor value calculated to provide ~10 mA of shunt diode bias current given  $V_{CC}$  = 5 V and  $V_{DD}$  = 120 V.

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.



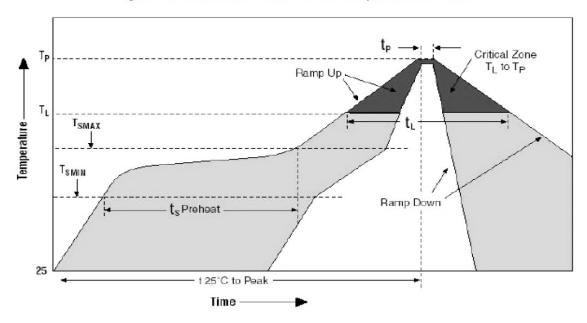
#### **Assembly Instructions**

SP2T PIN Diodes may be placed onto circuit boards with pick and place manufacturing equipment from tape and reel. The devices are attached to the circuit using conventional solder re-flow or wave soldering procedures with RoHS type or Sn 60 / Pb 40 type solders.

Profile Feature	SnPb Solder Assembly	Pb-Free Solder Assembly
Average Ramp-Up Rate $(T_{L} \text{ to } T_{p})$	3°C /second maximum	3°C /second maximum
Preheat:		
- Temperature Min (T <sub>SMIN</sub> )	100°C	150°C
- Temperature Max (T <sub>smax</sub> )	150°C	200°C
- Time (min to max)(t <sub>s</sub> )	60-120 s	60-180 s
T <sub>SMAX</sub> to T <sub>L</sub> - Ramp-Up Rate		3°C/s maximum
Time Maintained Above: - Temperature (Tլ) - Time (tլ)	<mark>183</mark> ℃ 60-150 s	217°C 60-150 s
Peak temperature (T <sub>P</sub> )	<mark>225</mark> +0/-5°C	260 +0/-5°C
Time Within 5°C of Actual Peak Temperature (t <sub>p</sub> )	10 – 30 s	20 – 40 s
Ramp-Down Rate	6°C /s maximum	6°C /s maximum
Time 25°C to Peak Temperature	6 minutes maximum	8 minutes maximum

Table 1. Time-Temperature Profile for Sn60/Pb40 or RoHS Type Solders

#### Figure 1. Solder Re-Flow Time-Temperature Profile



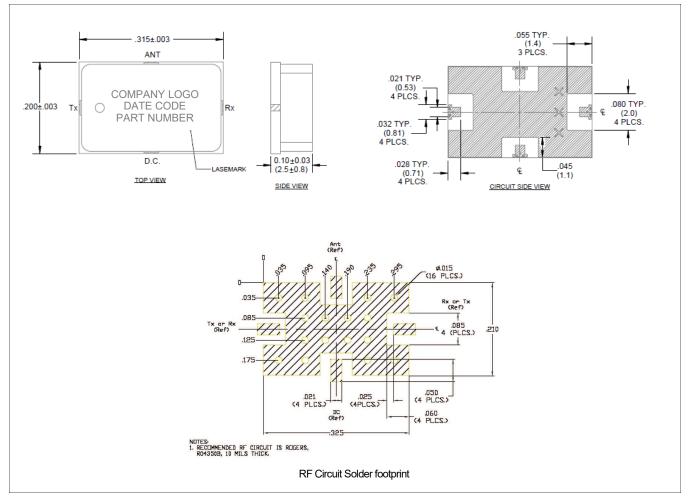
MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.

## **SP2T PIN Diode Switch**

# МАСОМ

#### MSW205x-205 Rev. V3

## Outline (CS205)<sup>10,11</sup>



10. Hatched metal area on circuit side of device is RF, DC and thermal grounded.

11. Vias should be solid copper fill and gold plated for optimum heat transfer from backside of switch module through Circuit Vias to metal thermal ground.

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.